## XMat Industry Day – Final Report

## Programme

## Institute of Materials 297 Euston Road, London, NW1 3AD

## 16 November 2017

10:00 am – 16:00 pm

10:00 – 10:30	Arrival and Refreshments
10:30 – 10:40	An introduction to the XMat programme Jon Binner
10:40 – 11:10	<i>Ultra-high temperature ceramic composite materials</i> , V Rubio Dias & J Binner, University of Birmingham, UK
11:10 – 11:30	<i>Current assisted processing, including flash sintering</i> , S Grasso, T Saunders & M Reece, Queen Mary University London, UK
11:30 – 11:50	<i>High Entropy Transition Metal Carbides</i> , EG Castle & M Reece, Queen Mary University London, UK
11:50 – 12:20	<i>Creep of HfB</i> <sub>2</sub> <i>-based UHTCs up to 2000<sup>o</sup>C</i> , E Zapata-Solvas, C Liu & WE Lee, Imperial College London, UK
12:20 – 12.50	<i>Theory and simulation of ultra-high-temperature ceramics</i> , T Mellan, T Davey, A Duff, S Azadi & MW Finnis, Imperial College London, UK
12:50 – 14:00	Lunch
14:00 – 14:20	Electronic structures and thermal properties of 312-MAX phases, S Azadi & MW Finnis, Imperial College London, UK
14:20 – 14:40	Measuring and Modelling the Thermo-mechanical Behaviour of Ceramics in Extreme Environments, L Larrimbe, S. Humphry- Baker, M.Pettina, J. Wang, D.D. Jayaseelan, WE Lee & L Vandeperre, Imperial College London, UK
14:40 – 15:00	Gel casting UHTC ceramics, J Zou & J Binner, University of
	Birmingham, UK
15:00 – 15:20	Birmingham, UK Optimisation of SiC <sub>f</sub> /SiC <sub>p</sub> /SiC preforms for microwave enhanced chemical vapour infiltration, M Porter, A D'Angió & J Binner, University of Birmingham, UK
15:00 – 15:20 15:20 – 15:30	Birmingham, UK <i>Optimisation of SiC</i> <sub>f</sub> /SiC <sub>p</sub> /SiC preforms for microwave enhanced chemical vapour infiltration, M Porter, A D'Angió & J Binner, University of Birmingham, UK <b>Tea</b>
15:00 – 15:20 15:20 – 15:30 15:30 – 16:00	Birmingham, UK <i>Optimisation of SiCt/SiCp/SiC preforms for microwave</i> <i>enhanced chemical vapour infiltration</i> , M Porter, A D'Angió & J Binner, University of Birmingham, UK <b>Tea</b> Open discussion: Where we are going next
15:00 – 15:20 15:20 – 15:30 15:30 – 16:00 16:00	Birmingham, UK <i>Optimisation of SiC<sub>f</sub>/SiC<sub>p</sub>/SiC preforms for microwave</i> <i>enhanced chemical vapour infiltration</i> , M Porter, A D'Angió & J Binner, University of Birmingham, UK <b>Tea</b> Open discussion: Where we are going next <b>Departure and optional visit to The Wellcome Collection</b>